

SEMICONDUCTOR

BCW32

NPN General Purpose Amplifier

- This device is designed for general purpose applications at collector currents to 300mA.
- Sourced from process 10.



BCW32

1. Base 2. Emitter 3. Collector

Absolute Maximum Ratings * T_a=25°C unless otherwise noted

Symbol	Parameter	Value	Units
CEO	Collector-Emitter Voltage	32	V
СВО	Collector-Base Voltage	32	V
EBO	Emitter-Base Voltage	5.0	V
;	Collector current (DC)	500	mA
J, T _{sta}	Operating and Storage Junction Temperature Range	-55 ~ +150	°C

NOTES:
1) These ratings are based on a maximum junction temperature of 150 degrees C.
2) These are state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

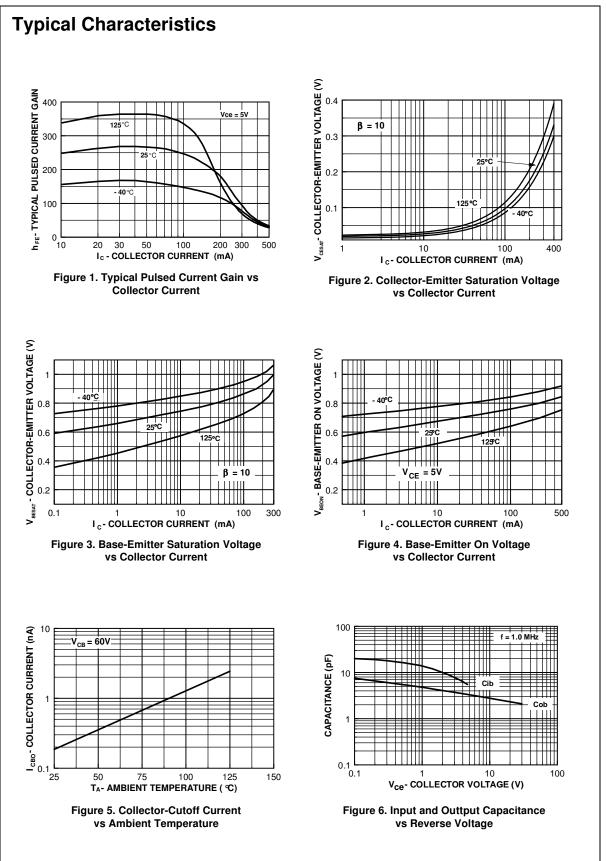
Electrical Characteristics Ta=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
Off Charact	eristics	•		•	•	
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_{\rm C} = 2.0 {\rm mA}, I_{\rm B} = 0$	32			V
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	$I_{\rm C} = 10 \mu {\rm A}, \ I_{\rm B} = 0$	32			V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_{\rm C} = 10 \mu {\rm A}, I_{\rm C} = 0$	5.0			V
I _{CBO}	Collector Cutoff Current	$V_{CB} = 32V, I_E = 0$ $V_{CB} = 32V, I_E = 0, T_A = 100^{\circ}C$			100 10	nA μA
On Charact	eristics					
h _{FE}	DC Current Gain	$I_{C} = 2.0 \text{mA}, V_{CE} = 5.0 \text{V}$	200		450	
V _{CE(sat)}	Collector-Emitter Saturation Voltage	$I_{\rm C} = 10 {\rm mA}, I_{\rm B} = 0.5 {\rm mA}$			0.25	V
V _{BE(on)}	Base-Emitter On Voltage	$I_{C} = 2.0 \text{mA}, V_{CE} = 5.0 \text{V}$	0.55		0.7	V
Small Signa	al Characteristics					
f _T	Current Gain Bandwidth Product	I _C = 2.0mA, V _{CE} = 5.0V f = 35MHz	200			
C _{obo}	Output Capacitance	V _{CB} = 10V, I _E = 0, f = 1.0MHz			4.0	pF
NF	Noise Figure	$I_{C} = 0.2 \text{mA}, V_{CE} = 5.0 \text{V}$ $R_{S} = 2.0 \text{k}\Omega, \text{f} = 1.0 \text{kHz}$ $B_{W} = 200 \text{Hz}$			10	dB

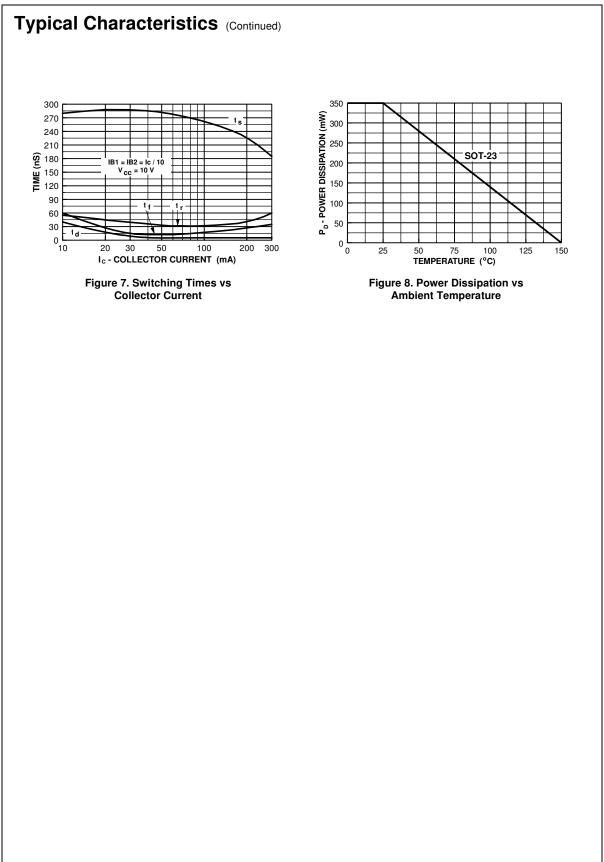
Thermal Characteristics TA=25°C unless otherwise noted

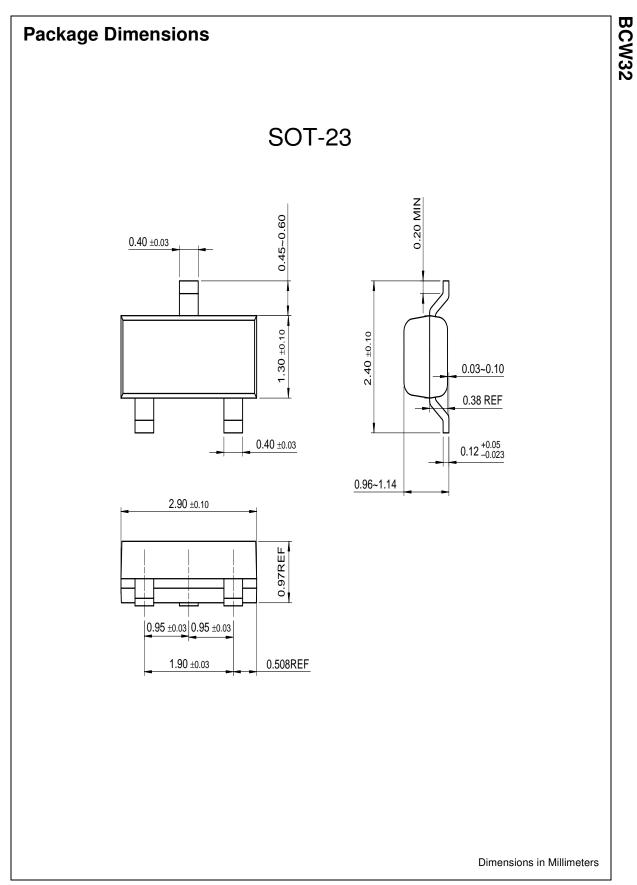
Symbol	Parameter	Max.	Units
PD	Total Device Dissipation	350	mW
-	Derate above 25°C	2.8	mW/°C
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	357	°C/W
Device mounted on	FR-4PCB 40mm \times 40mm \times 1.5mm		

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